DM74S20 Dual 4-Input NAND Gate

#### FAIRCHILD SEMICONDUCTOR

# **DM74S20 Dual 4-Input NAND Gate**

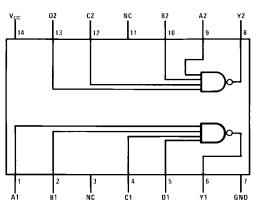
#### **General Description**

This device contains two independent gates each of which performs the logic NAND function.

# **Ordering Code:**

Order Number	Package Number	Package Description
DM74S20N	N14A	14-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

# **Connection Diagram**



### **Function Table**

Y = ABCD							
	Inputs						
Α	В	С	D	Y			
Х	Х	Х	L	Н			
Х	Х	L	Х	н			
Х	L	Х	Х	н			
L	Х	Х	Х	н			
Н	Н	Н	Н	L			

H = HIGH Logic Level L = LOW Logic Level X = Either LOW or HIGH Logic Level



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#### Absolute Maximum Ratings(Note 1)

Supply Voltage	7V
Input Voltage	5.5V
Operating Free Air Temperature Range	$0^{\circ}C$ to $+70^{\circ}C$
Storage Temperature Range	-65°C to +150°C

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

# **Recommended Operating Conditions**

Symbol	Parameter	Min	Nom	Max	Units
V <sub>CC</sub>	Supply Voltage	4.75	5	5.25	V
VIH	HIGH Level Input Voltage	2			V
V <sub>IL</sub>	LOW Level Input Voltage			0.8	V
он	HIGH Level Output Current			-1	mA
I <sub>OL</sub>	LOW Level Output Current			20	mA
T <sub>A</sub>	Free Air Operating Temperature	0		70	°C

### **Electrical Characteristics**

over recommended operating free air temperature (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ (Note 2)	Max	Units
VI	Input Clamp Voltage	$V_{CC} = Min, I_I = -18 \text{ mA}$			-1.2	V
V <sub>OH</sub>	HIGH Level Output Voltage	$V_{CC} = Min, I_{OH} = Max$ $V_{IL} = Max$	2.7	3.4		V
V <sub>OL</sub>	LOW Level Output Voltage	$V_{CC} = Min, I_{OL} = Max$ $V_{IH} = Min$			0.5	V
l <sub>l</sub>	Input Current @ Max Input Voltage	$V_{CC} = Max, V_I = 5.5V$			1	mA
I <sub>IH</sub>	HIGH Level Input Current	$V_{CC} = Max, V_I = 2.7V$			50	μΑ
IIL	LOW Level Input Current	$V_{CC} = Max, V_I = 0.5V$			-2	mA
los	Short Circuit Output Current	V <sub>CC</sub> = Max (Note 3)	-40		-100	mA
I <sub>CCH</sub>	Supply Current with Outputs HIGH	V <sub>CC</sub> = Max	İ	5	8	mA
I <sub>CCL</sub>	Supply Current with Outputs LOW	V <sub>CC</sub> = Max	İ	10	18	mA

Note 2: All typicals are at  $V_{CC}$  = 5V,  $T_A$  = 25°C.

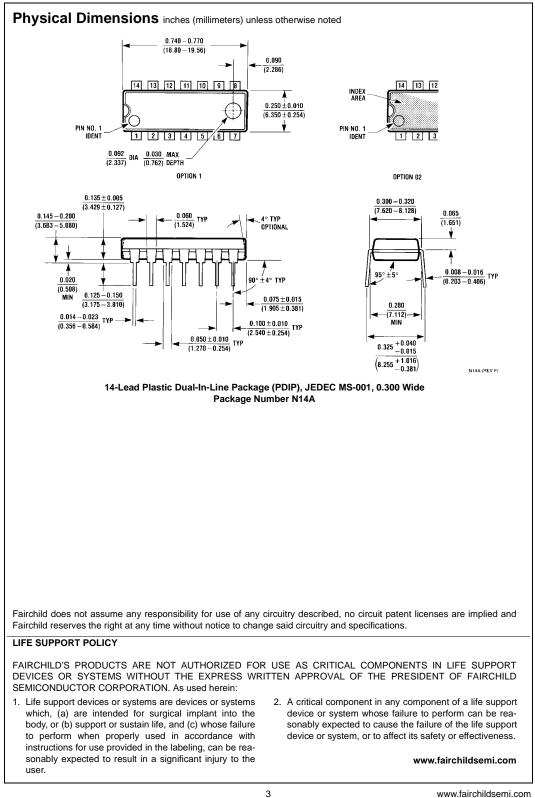
Note 3: Not more than one output should be shorted at a time, and the duration should not exceed one second.

### **Switching Characteristics**

at V\_{CC} = 5V and T\_A = 25^{\circ}C

		$R_L = 280\Omega$				
Symbol	Parameter	C <sub>L</sub> = 15 pF		$C_L = 50 \text{ pF}$		Units
		Min	Max	Min	Max	
t <sub>PLH</sub>	Propagation Delay Time	2	4.5	2	7	ns
	LOW-to-HIGH Level Output	2	4.5	2	'	113
t <sub>PHL</sub>	Propagation Delay Time	2	5	2	8	20
	HIGH-to-LOW Level Output	2	5	2	0	ns

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